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"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "<u>Embedded -</u> <u>Microcontrollers</u>"

Details

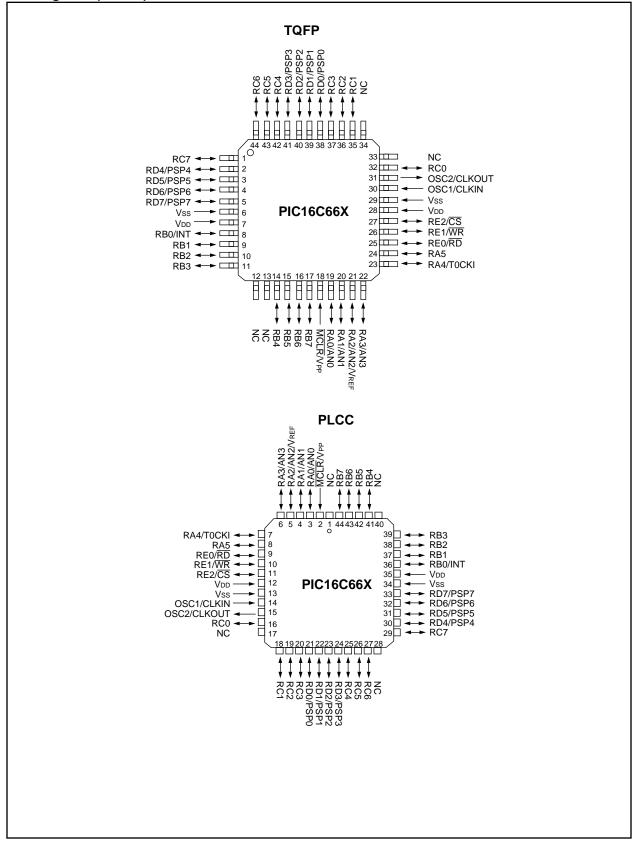
Product Status	Active
Core Processor	PIC
Core Size	8-Bit
Speed	4MHz
Connectivity	-
Peripherals	Brown-out Detect/Reset, LED, POR, WDT
Number of I/O	33
Program Memory Size	7KB (4K x 14)
Program Memory Type	OTP
EEPROM Size	-
RAM Size	176 x 8
Voltage - Supply (Vcc/Vdd)	4V ~ 6V
Data Converters	-
Oscillator Type	External
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Through Hole
Package / Case	40-DIP (0.600", 15.24mm)
Supplier Device Package	40-PDIP
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/pic16c662-04i-p

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

PIC16C64X & PIC16C66X

Pin Diagrams (Cont.'d)



1.0 GENERAL DESCRIPTION

PIC16C64X & PIC16C66X devices are 28-pin and 40-pin EPROM-based members of the versatile PIC16CXXX family of low-cost, high-performance, CMOS, fully-static, 8-bit microcontrollers.

All PIC16/17 microcontrollers employ an advanced RISC architecture. The PIC16CXXX family has enhanced core features, eight-level deep stack, and multiple internal and external interrupt sources. The separate instruction and data buses of the Harvard architecture allow a 14-bit wide instruction word with the separate 8-bit wide data. The two-stage instruction pipeline allows all instructions to execute in a single-cycle, except for program branches (which require two cycles). A total of 35 instructions (reduced instruction set) are available. Additionally, a large register set gives some of the architectural innovations used to achieve a very high performance.

PIC16CXXX microcontrollers typically achieve a 2:1 code compression and a 4:1 speed improvement over other 8-bit microcontrollers in its class.

The PIC16C641 has 128 bytes of RAM and the PIC16C642 has 176 bytes of RAM. Both devices have 22 I/O pins, and an 8-bit timer/counter with an 8-bit programmable prescaler. In addition, they have two analog comparators with a programmable on-chip voltage reference module. Program Memory has internal parity error detection circuitry with a Parity Error Reset. The comparator module is ideally suited for applications requiring a low-cost analog interface (e.g., battery chargers, threshold detectors, white goods controllers, etc.).

The PIC16C661 has 128 bytes of RAM and the PIC16C662 has 176 bytes of RAM. Both devices have 33 I/O pins, and an 8-bit timer/counter with an 8-bit programmable prescaler. They also have an 8-bit Parallel Slave Port. In addition, the devices have two analog comparators with a programmable on-chip voltage reference module. Program Memory has internal parity error detection circuitry with a Parity Error Reset. The comparator module is ideally suited for applications requiring a low-cost analog interface (e.g., battery threshold detectors, chargers. white goods controllers, etc.).

PIC16CXXX devices have special features to reduce external components, thus reducing cost, enhancing system reliability and reducing power consumption. There are four oscillator options, of which the single pin RC oscillator provides a low-cost solution, the LP oscillator minimizes power consumption, XT is a standard crystal, and the HS is for High Speed crystals. The SLEEP (power-down) mode offers power saving. The user can wake-up the chip from SLEEP through several external and internal interrupts and resets. A highly reliable Watchdog Timer (WDT) with its own on-chip RC oscillator provides protection against software lock-up.

A UV-erasable CERDIP-packaged version is ideal for code development while the cost-effective One-Time Programmable (OTP) version is suitable for production in any volume.

The PIC16CXXX series fit perfectly in applications ranging from battery chargers to low-power remote sensors. The EPROM technology makes customization of application programs (detection levels, pulse generation, timers, etc.) extremely fast and convenient. The small footprint packages make this microcontroller series perfect for all applications with space limitations. Low-cost, low-power, high-performance, ease of use, and I/O flexibility make the PIC16C64X & PIC16C66X very versatile.

1.1 Family and Upward Compatibility

Those users familiar with the PIC16C5X family of microcontrollers will realize that this is an enhanced version of the PIC16C5X architecture. Please refer to Appendix A for a detailed list of enhancements. Code written for PIC16C5X can be easily ported to the PIC16C64X & PIC16C66X (Appendix B).

1.2 Development Support

PIC16C64X & PIC16C66X devices are supported by the complete line of Microchip Development tools, including:

- MPLAB Integrated Development Environment including MPLAB-Simulator.
- MPASM Universal Assembler and MPLAB-C Universal C compiler.
- PRO MATE II and PICSTART Plus device programmers.
- PICMASTER In-circuit Emulator System
- *fuzzy*TECH-MP Fuzzy Logic Development Tools
- DriveWay Visual Programming Tool

Please refer to Section 11.0 for more details about these and other Microchip development tools.

6.3.1 SWITCHING PRESCALER ASSIGNMENT

The prescaler assignment is fully under software control, i.e., it can be changed "on the fly" during program execution.

Note: To avoid an unintended device RESET, the following instruction sequence (shown in Example 6-1) must be executed when changing the prescaler assignment from Timer0 to the WDT. This precaution must be followed even if the WDT is disabled.

EXAMPLE 6-1: CHANGING PRESCALER (TIMER0 \rightarrow WDT)

BCF	STATUS, RPO	;Bank 0
CLRF	TMR0	;Clear TMR0 & Prescaler
BSF	STATUS, RPO	;Bank 1
CLRWDT		;Clears WDT
MOVLW	b'xxxx1xxx'	;Select new prescale
MOVWF	OPTION_REG	;value & WDT
BCF	STATUS, RPO	;Bank 0

To change prescaler from the WDT to the Timer0 module, use the sequence shown in Example 6-2.

EXAMPLE 6-2: CHANGING PRESCALER (WDT \rightarrow TIMER0)

CLRWDT		;Clear WDT and
		;prescaler
BSF	STATUS, RPO	;Bank 1
MOVLW	b'xxxx0xxx'	;Select TMR0, new
		;prescale value and
MOVWF	OPTION_REG	;clock source
BCF	STATUS, RPO	;Bank 0

TABLE 6-1:REGISTERS ASSOCIATED WITH TIMER0

Address	Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Value on: POR, BOR	Value on all other resets
01h	TMR0	Timer0	Timer0 module's register xxxx xxx						xxxx xxxx	uuuu uuuu	
0Bh/8Bh	INTCON	GIE	PEIE	TOIE	INTE	RBIE	TOIF	INTF	RBIF	0000 000x	0000 000u
81h	OPTION	RBPU	INTEDG	TOCS	TOSE	PSA	PS2	PS1	PS0	1111 1111	1111 1111
85h	TRISA	—	_	TRISA5	TRISA4	TRISA3	TRISA2	TRISA1	TRISA0	11 1111	11 1111

Legend: x = unknown, u = unchanged, - = unimplemented locations read as '0'. Shaded cells are not used by Timer0.

7.6 Comparator Interrupts

The comparator interrupt flag is set whenever there is a change in the output value of either comparator. User software will need to maintain information about the status of the output bits, as read from CMCON<7:6>, to determine the actual change that has occurred. The CMIF bit (PIR1<6>), is the comparator interrupt flag and must be cleared in user software.

To enable the Comparator interrupt the following bits must be set:

- CMIE (PIE1<6>)
- PEIE (INTCON<6>)
- GIE (INTCON<7>)

The user, in the interrupt service routine, can clear the interrupt in the following manner:

- a) Any read or write of CMCON. This will end the mismatch condition.
- b) Clear flag bit CMIF.

A mismatch condition will continue to set flag bit CMIF. Reading CMCON will end the mismatch condition, and allow flag bit CMIF to be cleared.

7.7 Comparator Operation During SLEEP

When a comparator is active and the device is placed in SLEEP mode, the comparator remains active and the interrupt is functional if enabled. This interrupt will wake up the device from SLEEP mode when enabled. While the comparator is powered up, higher sleep currents than shown in the power-down current specification will occur. Each comparator that is operational will consume additional current as shown in the comparator specifications. To minimize power consumption while in SLEEP mode, turn off the comparators, CM2:CM0 = 111, before entering sleep. If the device wakes up from sleep, the contents of the CMCON register are not affected.

7.8 Effects of a RESET

A device reset forces the CMCON register to its reset state. This forces the comparator module to be in the comparator reset mode, CM2:CM0 = 000. This ensures that all potential inputs are analog inputs. Device current is minimized when analog inputs are present at reset time. The comparators will be powered down during the reset interval.

7.9 <u>Analog Input Connection</u> <u>Considerations</u>

A simplified circuit for an analog input is shown in Figure 7-5. Since the analog pins are connected to a digital output, they have reverse biased diodes to VDD and Vss. The analog input therefore, must be between Vss and VDD. If the input voltage deviates from this range by more than 0.6V in either direction, one of the diodes is forward biased and a latch-up may occur. A maximum source impedance of 10 kΩ is recommended for the analog sources. Any external component connected to an analog input pin, such as a capacitor or a Zener diode, should have very little leakage current.

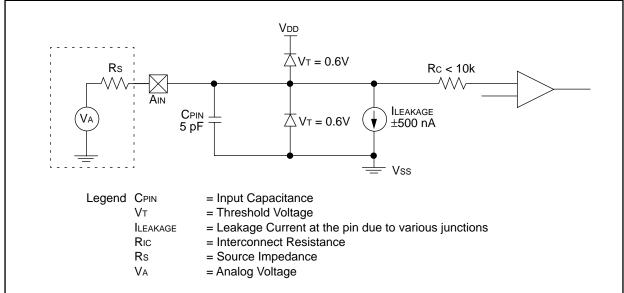


FIGURE 7-5: ANALOG INPUT MODEL

9.1 <u>Configuration Bits</u>

The configuration bits can be programmed (read as '0') or left unprogrammed (read as '1') to select various device configurations. These bits are mapped in program memory location 2007h.

FIGURE 9-1: CONFIGURATION WORD

The user will note that address 2007h is beyond the user program memory space. In fact, it belongs to the special test/configuration memory space (2000h–3FFFh), which can be accessed only during programming.

CP1	CPO	CP1	CP0	CP1	CP0	MPEEN	BODEN	CP1	CP0	PWRTE	WDTE	FOSC1	FOSC0	CONFIG	Address
bit13													bit0	REGISTER:	2007h
bit 13-		CP1:CF				oits ⁽²⁾									
5-4	4:	11 = Co 10 = Up				emory cod	le protecte	d							
		01 = Up	per 3/4	th of pr	ogram i	memory co									
		00 = All		,	•										
bit 7:		MPEEN				Enable s enabled									
						s disabled									
bit 6:					eset En	able bit (1)									
		1 = BOF 0 = BOF													
bit 3:						ble bit (1)									
DIL 3.		1 = PWI													
		0 = PWI	RT enal	oled											
bit 2:		WDTE : 1 = WD			er Enat	ole bit									
		1 = WD 0 = WD													
bit 1-0	D:	FOSC1:	FOSCO	: Oscill	ator Se	lection bits	6								
		11 = RC													
		10 = HS 01 = XT													
		00 = LP													
Note	1:	Enabling	Brown	n-out Ré	eset au	tomatically	enables t	ne Pov	/er-up T	imer (PWF	RT) regar	tless of th	e value of l	bit PWRTE. Ens	ure the
NOIG						iytime Bro					(i) iogait			SICT WITTE. EIIS	
	2:	All of the	e CP1:0	CP0 pai	rs have	to be give	n the sam	e value	e to ena	ble the coo	de protect	ion schen	ne listed.		

9.2 Oscillator Configurations

9.2.1 OSCILLATOR TYPES

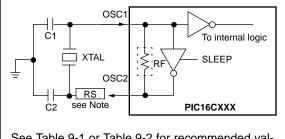
The PIC16CXXX can be operated in four different oscillator modes. The user can program two configuration bits (FOSC1 and FOSC0) to select one of these four modes:

- LP Low Power Crystal
- XT Crystal/Resonator
- HS High Speed Crystal/Resonator
- RC Resistor/Capacitor

9.2.2 CRYSTAL OSCILLATOR / CERAMIC RESONATORS

In XT, LP or HS modes a crystal or ceramic resonator is connected to the OSC1 and OSC2 pins to establish oscillation (Figure 9-2). The PIC16CXXX oscillator design requires the use of a parallel cut crystal. Use of a series cut crystal may give a frequency out of the crystal manufacturers specifications. When in XT, LP or HS modes, the device can have an external clock source to drive the OSC1 pin (Figure 9-3).

FIGURE 9-2: CRYSTAL OPERATION (OR CERAMIC RESONATOR) (HS, XT OR LP OSC CONFIGURATION)



See Table 9-1 or Table 9-2 for recommended values of C1 and C2.

Note: A series resistor may be required for AT strip cut crystals.

FIGURE 9-3: EXTERNAL CLOCK INPUT OPERATION (HS, XT OR LP OSC CONFIGURATION)

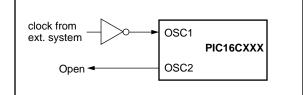


TABLE 9-1: CAPACITOR SELECTION FOR CERAMIC RESONATORS (PRELIMINARY)

Ranges tested:						
Mode	Freq	0	SC1			
XT	455 kHz	22 - 100				
	2.0 MHz	15 - 68 pl	F			
	4.0 MHz	15 - 68 p	F			
HS	8.0 MHz	10 - 68 p	F			
	16.0 MHz	10 - 22 p	F			
Note: Recommended values of C1 and C2 are identical to the ranges tested table. Higher capacitance increases the stability of the oscillator but also increases the start-up time. These values are for design guidance only. Since each resonator has its own characteristics, the user should consult the resonator manufacturer for appropriate values of external components.						
Resonators used:						
455 kHz Panasonic EFO		55K04B	±0.3%			
2.0 MHz	Murata Erie CSA2.	00MG	±0.5%			

400 KHZ	Fanasonic EFO-A400K04D	±0.3%			
2.0 MHz	Murata Erie CSA2.00MG	±0.5%			
4.0 MHz	Murata Erie CSA4.00MG	±0.5%			
8.0 MHz Murata Erie CSA8.00MT ±0.4		±0.5%			
16.0 MHz Murata Erie CSA16.00MX ±0.5%					
All resonators used did not have built-in capacitors.					

TABLE 9-2: CAPACITOR SELECTION FOR CRYSTAL OSCILLATOR (PRELIMINARY)

Mode	Freq	OSC1	OSC2
LP	32 kHz	68 - 100 pF	68 - 100 pF
	200 kHz	15 - 30 pF	15 - 30 pF
XT	100 kHz	68 - 150 pF	150 - 200 pF
	2 MHz	15 - 30 pF	15 - 30 pF
	4 MHz	15 - 30 pF	15 - 30 pF
HS	8 MHz	15 - 30 pF	15 - 30 pF
	10 MHz	15 - 30 pF	15 - 30 pF
	20 MHz	15 - 30 pF	15 - 30 pF

Higher capacitance increases the stability of the oscillator but also increases the start-up time. These values are for design guidance only. Rs may be required in HS mode as well as XT mode to avoid overdriving crystals with low drive level specification. Since each crystal has its own characteristics, the user should consult the crystal manufacturer for appropriate values of external components.

Crystals used:						
32.768 kHz	Epson C-001R32.768K-A	± 20 PPM				
100 kHz	Epson C-2 100.00 KC-P	± 20 PPM				
200 kHz	STD XTL 200.000 kHz	± 20 PPM				
2.0 MHz	ECS ECS-20-S-2	± 50 PPM				
4.0 MHz	ECS ECS-40-S-4	± 50 PPM				
10.0 MHz	ECS ECS-100-S-4	± 50 PPM				
20.0 MHz	ECS ECS-200-S-4	± 50 PPM				

9.4.5 PARITY ERROR RESET (PER)

PIC16C64X & PIC16C66X devices have on-chip parity bits that can be used to verify the contents of program memory. Parity bits may be useful in applications in order to increase overall reliability of a system.

There are two parity bits for each word of Program Memory. The parity bits are computed on alternating bits of the program word. One computation is performed using even parity, the other using odd parity. As a program executes, the parity is verified. The even parity bit is XOR'd with the even bits in the program memory word. The odd parity bit is negated and XOR'd with the odd bits in the program memory word. When an error is detected, a reset is generated and the PER flag bit in the PCON register is set. This indication can allow software to act on a failure. However, there is no indication of the program memory location of the failure of the Program Memory. This flag can only be cleared in software or by a POR.

The parity array is user selectable during programming. Bit7 of the configuration word located at address 2007h can be programmed (read as '0') to disable parity checking. If left unprogrammed (read as '1'), parity checking is enabled.

9.4.6 TIME-OUT SEQUENCE

On power-up, the time-out sequence is as follows: First PWRT time-out is invoked after POR has expired. Then the OST is activated. The total time-out will vary based on oscillator configuration and <u>PWRTE</u> bit status. For example, in RC mode with the <u>PWRTE</u> bit set (PWRT disabled), there will be no time-out at all. Figure 9-9, Figure 9-10 and Figure 9-11 depict time-out sequences.

Since the time-outs occur from the POR pulse, if $\overline{\text{MCLR}}$ is kept low long enough, the time-outs will expire. Then bringing $\overline{\text{MCLR}}$ high will begin execution immediately (Figure 9-10). This is useful for testing purposes or to synchronize more than one device operating in parallel.

Table 9-5 shows the reset conditions for some special registers, while Table 9-6 shows the reset conditions for all the registers.

TABLE 9-3: TIME-OUT IN VARIOUS SITUATIONS

9.4.7 POWER CONTROL/STATUS REGISTER (PCON)

The power control/status register, PCON (address 8Eh) has four bits. See Figure 4-10 for register.

Bit0 is \overline{BOR} (Brown-out Reset). \overline{BOR} is unknown on a Power-on-reset. It must initially be set by the user and checked on subsequent resets to see if $\overline{BOR} = '0'$ indicating that a Brown-out Reset has occurred. The \overline{BOR} status bit is a "don't care" bit and is not necessarily predictable if the brown-out circuit is disabled (by clearing the BODEN bit in the Configuration word).

Bit1 is POR (Power-on Reset). It is cleared on a Power-on Reset and is unaffected otherwise. The user set this bit following a Power-on Reset. On subsequent resets if POR is '0', it will indicate that a Power-on Reset must have occurred.

Bit2 is PER (Parity Error Reset). It is cleared on a Parity Error Reset and must be set by user software. It will also be set on a Power-on Reset.

Bit7 is MPEEN (Memory Parity Error Enable). This bit reflects the status of the MPEEN bit in configuration word. It is unaffected by any reset or interrupt.

Oscillator Configuration	Powe	er-up	Brown-out Reset	Wake-up	
	PWRTE = 0	PWRTE = 1	Brown-out Reset	from SLEEP	
XT, HS, LP	72 ms + 1024 Tosc	1024 Tosc	72 ms + 1024 Tosc	1024 Tosc	
RC	72 ms	_	72 ms	—	

PIC16C64X & PIC16C66X

SUBLW	Subtract W from Literal	SUBWF	Subtract W from f
Syntax:	[<i>label</i>] SUBLW k	Syntax:	[label] SUBWF f,d
Operands:	$0 \le k \le 255$	Operands:	$0 \le f \le 127$
Operation:	$k \text{ - } (W) \to (W)$		d ∈ [0,1]
Status	C, DC, Z	Operation:	(f) - (W) \rightarrow (dest)
Affected:		Status Affected:	C, DC, Z
Encoding:	11 110x kkkk kkkk		
Description:	The W register is subtracted (2's com- plement method) from the eight bit literal 'k'. The result is placed in the W register.	Encoding: Description:	00 0010 dfff ffff Subtract (2's complement method) W register from register 'f'. If 'd' is 0 the result is
Words:	1		stored in the W register. If 'd' is 1 the result is stored back in register 'f'.
Cycles:	1	Words:	1
Example 1:	SUBLW 0x02	Cycles:	1
	Before Instruction	Example 1:	SUBWF REG1,1
	W = 1		Before Instruction
	C = ?		REG1 = 3
	After Instruction		W = 2
	W = 1 C = 1; result is positive		C = ?
Example 2:	Before Instruction		After Instruction
	W = 2		REG1 = 1 W = 2
	C = ?		C = 2 C = 1; result is positive
	After Instruction	Example 2:	Before Instruction
	W = 0		REG1 = 2
-	C = 1; result is zero		W = 2 $C = ?$
Example 3:	Before Instruction		After Instruction
	W = 3 $C = ?$		REG1 = 0
	After Instruction		W = 2
	W = 0xFF		C = 1; result is zero
	C = 0; result is nega-	Example 3:	Before Instruction
	tive		REG1 = 1 W = 2
			$ \begin{array}{llllllllllllllllllllllllllllllllllll$
			After Instruction
			REG1 = 0xEE

REG1	=	0xFF
W	=	2
С	=	0; result is negative

NOTES:

12.2 DC Characteristics: PIC16LC641/642/661/662-04 (Commercial, Industrial)

		Standard Operating Conditions (unless	otherwi	se sta	ted)	
		Operating temperature -40° C				industr	ial and
		0°C	\leq TA \leq	+70°C	COI	nmerci	al
Param No.	Sym	Characteristic	Min	Тур†	Max	Units	Conditions
D001	Vdd	Supply Voltage	3.0	_	6.0	V	XT, RC, and LP osc configuration
D002*	Vdr	RAM Data Retention Voltage ⁽¹⁾	1.5	_	-	V	Device in SLEEP mode
D003	VPOR	VDD start voltage to ensure internal Power-on Reset signal	-	Vss	-	V	See section on Power-on Reset for details
D004*	SVDD	VDD rise rate to ensure internal Power-on Reset signal	0.05	_	_	V/ms	See section on Power-on Reset for details
D005	VBOR	Brown-out Reset Voltage	3.7	4.0	4.3	V	BODEN configuration bit is clear
D010	IDD	Supply Current ⁽²⁾	_	2.0	3.8	mA	XT and RC osc configuration Fosc = 4.0 MHz, VDD = 3.0V, WDT disabled ⁽⁴⁾
D010A			_	22.5	48	μΑ	LP ose configuration Fose = 32 kHz, VDD = 3.0V, WD7 disabled
		Module Differential Current (5)		\square	\checkmark		
D015	Δ IBOR	Brown-out Reset Current		350	425	μA	BODEN bit is clear, VDD = 5.0V
D016		Comparator Current for each Comparator	$\left \begin{array}{c} \\ \end{array} \right $		100	μA	VDD = 3.0V
D017	Δ IVREF	VREF Current		$\langle \mathcal{L} \rangle$	300	μA	VDD = 3.0V
D021	ΔIWDT	WDT Current 🧹 🥆		6.0>	20	μA	VDD = 3.0V
D021	IPD	Power-down Current (3)	$\left \right\rangle$	Ø.9	5	μA	VDD = 3.0V, WDT disabled

* These parameters are characterized but not tested.

† Data in "Typ" column is at 5.0V, 25°C, unless otherwise stated. These parameters are for design guidance only and are not tested.

Note 1: This is the limit to which Voo can be Jowered in SLEEP mode without losing RAM data.

2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as I/O pin loading and switching rate, oscillator type, internal code execution pattern, and temperature also have an impact on the surrent consumption.

The test conditions for all Job measurements in active operation mode are:

OSC1=external square wave, from rail to rail; all I/O pins tristated, pulled to VDD,

 $\overline{\text{MCLR}} = \sqrt{\text{DD}}$; $\overline{\text{WRT}}$ enabled/disabled as specified.

The power down current in SLEEP mode does not depend on the oscillator type. Power-down current is measured with the part in SLEEP mode, with all I/O pins in hi-impedance state and tied to VDD or Vss.
 For RC osc configuration, current through Rext is not included. The current through the resistor can be

< estimated by the formula Ir = VDD/2Rext (mA) with Rext in k Ω . 5: The Δ current is the additional current consumed when this peripheral is enabled. This current should be

added to the base IDD or IPD measurement.

PIC16C64X & PIC16C66X

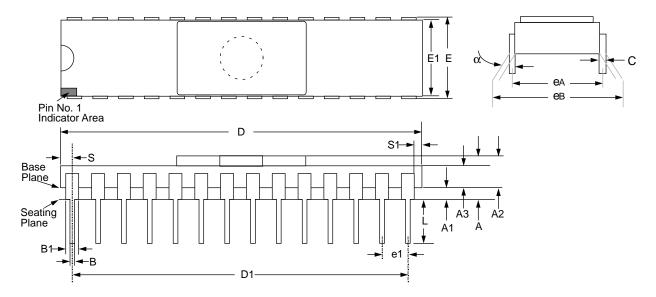
		Standard Operating Conditions (inless othe	rwico	stated)				
	Standard Operating Conditions (unless otherwise stated) Operating temperature $-40^{\circ}C \le TA \le +85^{\circ}C$ for industrial,								
		· • ·	\leq TA \leq +70		,	and			
		• •			,				
	$-40^{\circ}C \le TA \le +125^{\circ}C$ automotive Operating voltage VDD range as described in DC spec Section 12.1 and 12.2								
Param	Sym	Characteristic	Min	Тур	Max	Unit	Conditions		
No.				t					
	Vон	Output High Voltage ⁽³⁾							
D090		I/O ports (Except RA4)	Vdd-0.7	-	-	V	Юн = -3.0 mA, VpD = 4.5V,		
							-40° to +85°C		
			Vdd-0.7	-	-	V	Юн = -2.5 mA, \		
							$VDD = 4.5V, \mp 125^{\circ}C$		
D092		OSC2/CLKOUT	VDD-0.7	-	-	V	IOH = -1.3 mA, VDD=4.5V,		
							-40° to +85°C		
		(BC anh)	VDD-0.7	-	-	V <	$10 \mu = -1.0 \text{ mA},$		
		(RC only)					VDD ≠ 4,5V, +125°C		
		Capacitive Loading Specs			/				
		on Output Pins					\land		
D100	Cosc2	OSC2 pin	-	-	15 \	YOF>	In XT, HS and LP modes when		
							external clock used to drive OSC1.		
D101	Сю	All I/O pins/OSC2 (in RC mode)	-	-	50				

* These parameters are characterized but not tested.

† Data in "Typ" column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

Note 1: In RC oscillator configuration, the OSC1 pin is a Schmitt Trigger nput. It is not recommended that the PIC16C64X & PIC16C66X be driven with external clock in RC mode.

- 2: The leakage current on the MCLR pin is strongly dependent on applied voltage level. The specified levels represent normal operating conditions. Higher leakage current may be measured at different input voltages.
- 3: Negative current is defined as coming out of the pin



Package Type: 28-Lead Ceramic Side Brazed Dual In-Line with Window (JW) (300 mil)

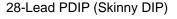
Package Group: Ceramic Side Brazed Dual In-Line (CER)							
O makes l		Millimeters		Inches			
Symbol	Min	Max	Notes	Min	Max	Notes	
α	0°	10°		0°	10°		
А	3.937	5.030		0.155	0.198		
A1	1.016	1.524		0.040	0.060		
A2	2.921	3.506		0.115	0.138		
A3	1.930	2.388		0.076	0.094		
В	0.406	0.508		0.016	0.020		
B1	1.219	1.321	Typical	0.048	0.052		
С	0.228	0.305	Typical	0.009	0.012		
D	35.204	35.916		1.386	1.414		
D1	32.893	33.147	BSC	1.295	1.305		
E	7.620	8.128		0.300	0.320		
E1	7.366	7.620		0.290	0.300		
e1	2.413	2.667	Typical	0.095	0.105		
eA	7.366	7.874	BSC	0.290	0.310		
eB	7.594	8.179		0.299	0.322		
L	3.302	4.064		0.130	0.160		
S	1.143	1.397		0.045	0.055		
S1	0.533	0.737		0.021	0.029		

D1 D D/2 PinNo. 1 Indicator Area REFERERE E1 E Ė/2 8 Places А /11/13° 0° min. Detail B A2 | Datum Plane 0.25 0.08 R min. Å1 . 0-7° with Lead Finish Gauge Plane 0.20 min-0.09/0.2 0.09/0.16 1.00 ref. **▲** b1 Base Metal DETAIL B

Package Type: 44-Lead Thin Plastic Quad Flatpack (PT/TQ) - 10x10x1 mm Body 1.0/0.10 mm Lead Form

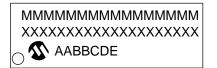
Package Group: Plastic TQFP							
		Millimeters		Inches			
Symbol	Min	Max	Notes	Min	Max	Notes	
α	0°	7 °		0°	7 °		
А		1.200		_	0.047		
A1	0.050	0.150		0.002	0.006		
A2	0.950	1.050		0.037	0.041		
b	0.300	0.450		0.012	0.018		
b1	0.300	0.400		0.012	0.016		
D	12.0	12.0	BSC	0.472	0.0472	BSC	
D1	10.0	10.0	BSC	0.394	0.394	BSC	
Е	12.0	12.0	BSC	0.472	0.472	BSC	
E1	10.0	10.0	BSC	0.394	0.394	BSC	
е	0.8	0.8	BSC	0.031	0.031	BSC	
L	0.450	0.750		0.018	0.030		

14.1 Package Marking Information





28-Lead SOIC



Example



Example



28-Lead Side Brazed Skinny Windowed



Example



 Legend:
 MM...MMicrochip part number information

 XX...X
 Customer specific information*

 AA
 Year code (last 2 digits of calendar year)

 BB
 Week code (week of January 1 is week '01')

 C
 Facility code of the plant at which wafer is manufactured

 C = Chandler, Arizona, U.S.A.

 D
 Mask revision number

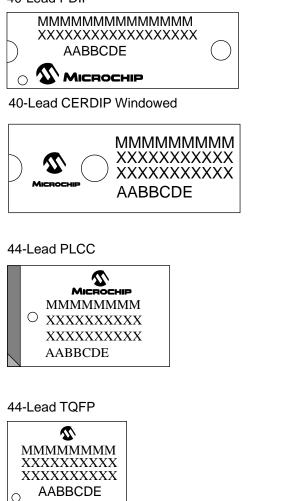
 E
 Assembly code of the plant or country of origin in which part was assembled

Note: In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line thus limiting the number of available characters for customer specific information.

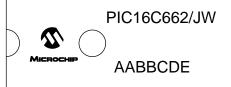
*Standard OTP marking consists of Microchip part number, year code, week code, facility code, mask rev#, and assembly code. For OTP marking beyond this, certain price adders apply. Please check with your Microchip Sales Office. For QTP devices, any special marking adders are included in QTP price.

14.2 Package Marking Information

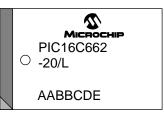
40-Lead PDIP



Example
PIC16C662-04/P
9512CAA
Similar Microchip
Example



Example



Example



Legend	: MMMMicrochip part number information
XXX	Customer specific information*
AA	Year code (last 2 digits of calendar year)
BB	Week code (week of January 1 is week '01')
С	Facility code of the plant at which wafer is manufactured
	C = Chandler, Arizona, U.S.A.
D	Mask revision number
E	Assembly code of the plant or country of origin in which
	part was assembled

Note: In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line thus limiting the number of available characters for customer specific information.

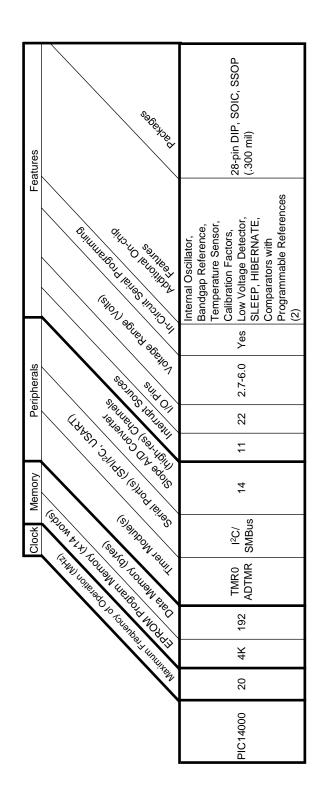
*Standard OTP marking consists of Microchip part number, year code, week code, facility code, mask rev#, and assembly code. For OTP marking beyond this, certain price adders apply. Please check with your Microchip Sales Office. For QTP devices, any special marking adders are included in QTP price.

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NOTES:

APPENDIX E: PIC16/17 MICROCONTROLLERS

E.1 PIC14000 Devices



READER RESPONSE

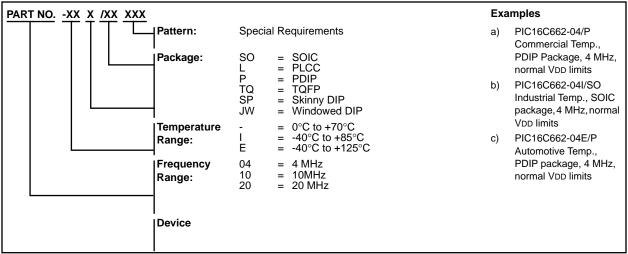
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NOTES:

PIC16C64X & PIC16C66X PRODUCT IDENTIFICATION SYSTEM



Please contact your local sales office for exact ordering procedures.

JW devices are UV erasable and can be programmed to any device configuration. JW devices meet the electrical requirements of each oscillator type (including LC devices).

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